LSDA+U approximation-based analysis of the electronic structure of C eFeG e₃

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Abstract

We perform ab initio electronic structure calculations of the intermetallic compound CeFeGe₃ by means of the Tight Binding Linear Mu n-Tin Orbitals-Atomic Sphere Approximation (TB-LMTO-ASA) within the Local Spin Density Approximation containing the so-called Hubbard correction term (LSDA+U^{SIC}), using the Stuttgart's TB (Tight Binding)-LMTO-ASA code in the fram ework of the Density Functional Theory (DFT).

KEYW ORDS: Ab initio calculations, LSDA+U approximation, interm etallic compound.

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1 Introduction

The heavy electron compounds refer to those having a speci c heat coe cient

of the order of $Jm \, ol^{1} \, K^{2}$, which is much larger than that of simple metals (being typically in the range of m Jm ol 1 K 2). In addition, this im plies that such compounds which have been given a great deal of attention for long time possess a large e ective mass m, outweighing several hundreds of times the free electron m ass [1]. They can be classi ed into two groups: the concentrated K ondo com pounds CK and the interm ediate valence com pounds (IV) [2,3] depending on the position of the 4f or 5f level, relative to the Ferm i level. The CK compounds have an integer valence at tem peratures much higher (T T_k) than the K ondo tem perature T_k , at which, there appears the K ondo e ect (an e ect observed in metals with a magnetic impurity). How ever, at comparatively T_k) they form a Fermi liquid state [4] with a reduction low tem peratures (T of its m agnetic m om ent. On the other hand, the IV com pounds do not possess an integer valence at room temperature as a result of the strong hybridization between the 4f electrons and the conduction electrons, due to the anom alous proximity between the 4f and the Fermi levels.

Remarkably, the CeFeGe₃ compound here studied [5] apparently gives rise to two behaviors: A high T_k of the order of 100 K and an integer valence for Ce at room temperature. This study is motivated by the fact that such compound is known to present a strong electronic correlation character, which occurs when the C oulom b repulsion between electrons strongly inhibits theirm otion, thus becom ing highly localized. Because of this, on compounds containing lanthanides the norm ally expected m etal behavior cerium ions with 4f electrons or uranium and neptunium ions with 5f electrons is not observed. Some examples are: CeA₁₃, CeCuSi₂, CeCu₆, UBe₁₃, UCd₁₁, U₂Zn₁₇ and NpBe₁₃, as well as transition m etal oxides, organic m etals and carbon compounds, i.e., carbon nanotubes, etc.

In the rst stage of the present work ab initio calculations were carried out to investigate the electronic structure of the interm etallic com pound C eFeG e₃ (tetragonal structure with spatial group 107) by using a DFT method [7] in the LM TO -A SA approximation [8], whereas in the second, an LSDA + U^{SIC} approximation [9] was used, as implemented in the Stuttgart's TB-LM TO -A SA code version 47 [8]. The density of states (DOS), total and partial, for cerium and iron, as well as the band structure (BS) are obtained from the compound geom etrical conformation optimized by the CASTEP program (C ambridge Serial Total Energy Package) which makes use of the ultrasoft pseudopotentials theory [10]. The C oulom b and exchange parameters used in the calculations were U = 5:4 eV [11] for cerium and U = 2:3 eV [12] (J = 0:9 eV) for iron, just obtained in the literature.

2 C om putational approach.

2.1 LM TO -A SA and CASTEP Calculations.

The LM TO -A SA approximation employs the unitary cell splitting into overlaping W igner-Seitz (W S) spheres with a maximum overlap of 15%, which is generally considered a reasonable approximation when having a spherically sym metric potential within the spheres. In addition, use ismade of the A SA (A tomic Sphere Approximation) condition, i.e., a spherical approximation containing no zone of free electrons on the M u n-T in structure. For open structures, as the ones here considered, a set of empty spheres is introduced as a device for describing the repulsion potentials in the interstices (between an atomic and an interstitial sphere an overlap of 20% is allowed). The total volume of the W S spheres is equal to the unit cell volume, thus eliminating the interstitial region.

On the other hand, the M u n-T in (M T) orbital is energy dependent with the following linearized form :

$$(\mathbf{r}) = i^{1} Y_{lm} (\mathbf{\hat{r}})$$

$$(E; r) + p_{n} (\mathbf{r} = S_{R})^{1} ; r < S_{R}$$

$$(S=r)^{1+1} ; r > S_{R}$$

$$(1)$$

where $f(\mathbf{r})$ is found by num erical solution of the radial Schrodinger equation, $f(\mathbf{r}) = RL \cdot R$ is the site index, whereas l and m are the orbital and m agnetic quantum numbers of the angular m on entum . The Y_{lm} 's refer to spherical harm onics and S_R is the M T radius. The num erical orbital $f(\mathbf{r})$ is augmented inside the sphere by a renorm alized spherical Bessel function,

$$J_{k^{n}}(\mathbf{r}) = i^{1}Y_{lm} \frac{(2l+1)!!}{kS_{R}} j_{l}(k\mathbf{r}); \qquad (2)$$

whereas outside the spheres, a renorm alized spherical Hankel function is added:

$$H_{k^{\wedge}}(\mathbf{r}) = i^{l}Y_{lm} \frac{(kS_{R})^{l+1}}{(2l-1)!!} h_{1}(k\mathbf{r}):$$
(3)

Here, $h_1 = j_1$ in h_1 is a linear combination of spherical Bessel and Neum ann functions. Thus, the tail of the MT orbitals at $r > S_R$ is the solution of the Helm holtz equation with zero kinetic energy. The potential parameters p_{-} are chosen so as to ensure that the wave function be continuous and di erentiable at the sphere boundary.

In this approximation the potential V_{xc} is either von Barth-Hedin (vBH)[13] or Vosko-Ceperly-Alder [14] type at the Local Spin Density Approximation (LSDA) level, whereas at the Generalized G radient Spin Approximation (GGS) level which is a functional containing a density gradient correction the potentials used the Langreth-MehlHu [15] or Perdew-W and type [16]. The exchange-correlation potential used in the present calculations corresponds to that containing the von Barth-Hedin parametrization, whose general form is

$$v_{xc} = A(r_s) \frac{2n}{n} + B(r_s);$$
 (4)

where A (r_s) and B (r_s) are analytical functions.

2.2 Geometry Optimization

The ternary system unit cellwas optimized by means of ab initio methods, based on a DFT treatment within the LocalSpin Density Approximation (LSDA) and with the Generalized Gradient Spin (GGS) approximation. In the CASTEP program [10] the wave function is expanded in planes waves for the valence electrons, whereas the core electrons (bound to the nucleus) are taken into account by means of their electrons (bound to the valence electrons, in the form of pseudopotentials which are added to the corresponding Kohn-Sham Hamiltonian.

The pseudopotentials used in this work were generated by Vanderbilt [17] in the K leinm an-Bylander [18] representation. The param etrizations of polarized spin developed by Perdew-Zunger [19] and Perdew-Burke-Emzerhof [20] for the exchange and correlation energy were used. The conjugated gradient method is employed to relax nuclear positions. The sam pling of the Brillouin zone was of 7 7 8 and 9 9 11 for the LSDA and GGS approximations, respectively, using the scheme of Monkhorst-Pack [21]. The cuto energy for the plane waves was of 400 eV approximately. Self-consistency in the calculations was attained whenever the total energy changes were 5 m eV, which corresponds to a criterion of reasonably good convergence.

To perform geometry optimization we let the lattice constants a; b and c vary as free parameters though they are expected to undergo changes no larger than 5% relative to the experimental values. The crystal energy is minimized with respect to the degrees of freedom by taking into account the calculation of H ellm ann-Feynm an forces in the atom s and the components of the stress tensor [22]. Finally, the utilized optimization criteria were 0.00002 eV, 0.0010 A and 0.050 eV/A for energy change, quadratic mean displacement, and quadratic mean force per atom, respectively.

2.3 M athematical Structure of the approximation LDA + U $^{\rm SIC}$

In the LSDA+U [9] method the electrons are separated into two subsystems (i and ii). For Ce, (i) delocalized s;p and d electrons, which are described by an orbital-independent one-electron potential (the LSDA potential), and (ii) localized 4f electrons, for which we take into account the orbital degeneracy and a Coulom b interaction of the form $\frac{1}{2}$ U $_{6}$ on n o, where n is the f-orbital (or d-orbital) occupancy. For Fe, (i) delocalized s;p electrons, and (ii) localized 3d electrons.

The Ham iltonian for the spin orbitally degenerate systems is of the form

$$H^{D} = \frac{X X X}{i_{j} \text{ mm}^{m}} t_{i_{j}}^{m \text{ m}^{m}} \hat{C}_{i_{m}}^{+} \hat{C}_{i_{m}} \circ + \frac{(U J)}{2} X X X \\ + \frac{U}{2} X X \\ i_{i_{m} \text{ m}^{n}} \hat{n}_{i_{m}} \hat{n}_{i_{m}} \circ$$
(5)

where $\hat{c}_{jm} \circ is$ an electron annihilation operator with an orbital index m and spin (= ;). In the lattice site $i;t_{ij}^{mm} \circ i$ are the hopping integrals and $\hat{n}_{im} \circ i$ is the number operator of the f (or d) electron at site i, orbital m with spin

. The rst term in Eq. (5) describes the hopping of electrons between lattice sites i and j; the interactions between the localized electrons are described by the second and third term s, where U and J represent the on-site C oulom b and exchange interaction, respectively.

If we want to correct the LSDA functional for localized electrons we must rst extract their LSDA treatment to avoid double count of the interaction. The spin density functional theory assumes a local exchange-correlation potential which is a function of the local charge and spin densities, so, uctuations around the average occupations are neglected. In the mean eld approximation (MFA) we can write

$$\hat{\mathbf{n}}_{m} \quad \hat{\mathbf{n}}_{m} \circ \circ = \hat{\mathbf{n}}_{m} \quad \mathbf{n}_{m} \circ \circ + \hat{\mathbf{n}}_{m} \circ \circ \mathbf{n}_{m} \qquad \mathbf{n}_{m} \quad \mathbf{n}_{m} \circ \circ \tag{6}$$

where n_m is the mean value of \hat{n}_m and $n = {P \atop m} n_m$. By introducing this approximation in Eq. (5), we obtain the expression for potential energy in the mean eld approximation,

$$E^{MF} = \frac{U \quad J^{X} \quad X}{2} \qquad n_{i} \quad (n_{i} \quad n_{im} \quad) + \frac{U \quad X \quad X}{2} \qquad n_{i} \quad n_{i} \quad (7)$$

Solvyev et al. [23] propose to extract an energy function from the total number of electrons per spin n_i which would act as the LSDA potential. Such expression can be obtained from Eq.(5) in the atom ic lim it where occupation of the individual particle n_i is either 0 or 1:

$$E_{cor}^{LSDA} = \frac{U}{2} \int_{i}^{X} n_{i} (n_{i} - 1) + \frac{U}{2} \int_{i}^{X} n_{i} n_{i}$$
(8)

This energy is now subtracted from $E^{M F}$ to obtain that associated with the total energy for localized states:

$$E = E^{MF} E_{cor}^{LSDA} = \frac{U J^{X}}{2} n_{i} (1 n_{im})$$
$$= \frac{U J^{X}}{2} (n_{im} r_{im}^{2}): (9)$$

The fraction of the potential acting on the localized orbital (m $\,$) is found by di erentiating Eq. (9) with respect to the occupation number $n_{\,\rm im}\,$:

$$\frac{d E}{d(n_{im})} = V_{im} = (U J) \frac{1}{2} n_{im} :$$
(10)

An orbital dependent one-electron potential is thus obtained.

3 Results and discussion.

3.1 First Stage: LM TO -A SA calculations

Results obtained in the optimization of the interm etallic compound CeFeGe3 are shown in Table II. The LSD and GGS approximations yield values below the experim ental param eters, which may be due to the fact that neither approximation removes the error introduced by the self-energy interaction term, arising from double count in the Ham iltonian. Furtherm ore, this material does not present a trend sim ilar to that of sem iconductors since otherw ise, the LSDA and GGA results would give values remaining below and above the experim ental parameters, respectively. A similar situation is found in the equilibrium properties of the plutonium (phase -Pu) [24], in which, results obtained with LDA and GGS give numbers that remain below the corresponding experimental values. We work with the CASTEP program at GGS level employing 446 Kpoints in the Brillouin zone. On the other hand, the density of states (total and partial) and band structure were obtained via the LMTO-ASA methodology within the DFT theory and the LSDA approximation, using the von Barth-Hedin param etrization at the optim ized unit cell geom etry. The corresponding results are com piled in Table I.

The total density of states (DOS) is given in Fig. 1, whereas the partial DOS associated with cerium f-states and iron d-states is illustrated in Figs. 2 and 3, respectively. They all indicate a metallic behavior for the material here analyzed, since we have the Ferm i level slightly displaced from the central band. This is also supported by boking at the plot of band states (BS), as shown in Fig. 4, where a dense concentration of bands due to the cerium f states occurs around the Ferm i level. Furtherm ore, the fact of having alm ost horizontal bands points to the characteristic behavior of a heavy ferm ion com pound (in our case, = 150 m J-m olK²) [1,5].

In the literature it is reported that the greater magnetic contribution stems from cerium (being the magnetic in purity responsible for the K ondo e ect); a fact that is corroborated in the present theoretical calculations (see Table I). Once optimized the geometrical parameters, the material here analyzed turns out to be one of those classified as an intermediate valence compound. In our calculation, C e has a magnetic moment of 0.00132 whereas the compound's total magnetic moment is 0.0010084. Therefore, according to the criterion proposed by V ildosola and L lois [25], i.e., by using calculations at the LSD A

level and the exchange-correlation potential of Perdew -W ang, they propose that the m aterials can be classi ed as follow s:

Itinerant if	Сe	=	0;	
Intermediate valence if	Сe	<	0:5 _в ;	(11)
M agnetic if	Се	>	0:5 _B	

A n interm ediate valence system is usually de ned in the literature as one having a noninteger average number off electrons. Note that the charge on the C e atom according with the LSD A calculation is of $2.4654 \, \mathrm{au.w}$ ith a magnetic moment of 0.00132. This means that the norm alatom con guration of [X e]4f¹5d¹6s² is being added with alm ost 3 electrons whose alpha and beta spins pair o one another, which results in an overall moment of nearly zero magnitude.

3.2 Second Stage: LSDA + U calculations

As can be inferred from the analysis presented in the previous stage, the DFT theory because of its intrinsic formulation it cannot deal properly with strongly correlated systems, therefore, we have chosen to resort to the LSDA + U^{SIC} approximation, developed by Anisim ov et al: [9], to calculate the electronic structure of the interm etallic compound C eF eG e₃, as in plemented in the Stuttgart's TB-LM TO-ASA code version 47. For this calculation, we employed the parameters reported in the literature: U = 5.4 eV [11] for cerium and U = 2.3 eV (J = 0.9 eV) [12] for iron.

The resulting density of states in this case is plotted in Fig. 5, whereas the partial DOS for cerium 4f-states and iron 3d-states are depicted in Figs. 6 and 7, respectively. By virtue of the approximation used in this stage, the latter include e ects arising from strong correlation, not accounted for in those obtained by means of a conventional DFT calculation. The corresponding band structure is displayed in Fig. 8.

In the display of total DOS the greatest contribution comes from the cerium 4f-states where an increased splitting within the energy bands in addition to a relative overall shift around the Ferm i level can be seen in Fig. 5. This feature also show sup in the partial density of states, where a large band energy splitting arising from the cerium 4f-states can be appreciated in Fig. 6 (being 5 eV wide, approximately), as compared with the corresponding energy band display (Fig. 2) obtained in the previous stage, in which, the presence of a nearly single peak dom inates, located very close and above the Ferm i level. The m agnetic contributions to thism aterial come parameter (previous stage), whereas the m agneticm on ent for germ anium is alm ost null, as seen in Table I. Furtherm ore, the m aterial presents m etallic behavior. When carrying out calculations with an exchange parameter J equal to 0.90 eV for iron there occurs a reduction of the m agnetic m om ent in a 42% rate, which probably follows from a slight localization e exchange to many the magnetic moment and the second second

concentration of energy bands occurring around the Ferm i level is consistent with a metallic behavior. In fact, a greater density of bands is observed in this stage (see Fig. 8) as compared to that observed without introducing the C oulom b parameter (see Fig. 4). Such feature in this stage points to a typical characteristic of heavy ferm ion materials.

A coording to the criterion mentioned in the rst stage, proposed by V ildosola and Llois [25], and extended to handle the total magnetic moment per unit cell, one can notice that the magnetic moments for cerium, 1:1407, iron, (0:6147), and 0:00055 for the empty spheres, give altogether a total moment of 0:552. This falls within the classication corresponding to an magnetic material. A lso, the charge distribution shown in Table I (empty spheres introduced by the ASA condition), points to a possible covalent character among the atoms of cerium, iron and germanium, although this manifests iself very weakly, despite the fact of accounting for correlation elects in the theoretical calculation. Comparing the charge of the Ce atom in the LSDA (vBH) and LSDA (vBH)+U cases, it is seen to be similar for both: 2.4654 a.u. and

2.3847 a.u., respectively. However, the U interaction gives rise to a complete change in the spin behavior: whereas in the absence of U almost 3 electrons are added to the neutral atom although the overallm agneticm om ent is nearly zero now the salient e ect in the presence of the U interaction is to align the electrons, yielding an electron agneticm om ent whose magnitude is 1:1407.

Having no charge di erence in the two cases, where the U interaction acts only on the f electrons, the lling of the f-shell proceeds via splitting of the and levels by the energy U and the occurrence of electron alignment on the f-shell only. The remaining charge distributes over the other shells: s, p and d.

4 Conclusions

The calculations perform ed by m eans of the LM TO -A SA approximation, within the DFT theory, lead to results that are similar to those reported in the literature, in particular, the obtained magnetic contribution of the compound here analyzed, which practically corresponds to that of a nonmagnetic material. On the other hand, the partial DOS, together with the band structure, show a metallic behavior for the latter. Furthermore, results obtained with calculations carried out where the C oulom b parameters U and J (for iron) are introduced, also favor a metallic behavior and, in addition, a heavy ferm ion character for this material. The two-stage analysis performed in the present study also indicates a small charge covalent character. The pronounced magnetic moment reduction occurring in iron is here ascribed to an electronic cloud localization on the 3d-shell of this atom, which arises as a direct consequence of taking into account strong electronic correlation e ects.

A cknow ledgm ents

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Table and gure captions

Table I: Parameters utilized in the electronic structure calculations of the ternary compound CeFeGe $_3$ and theoretical data obtained by using the TB-LMTO-ASA approach.

Table II: Cell parameters optimized by means of the CASTEP program.

F ig. 1: Total density of states of CeFeG e_3 obtained by the LSDA –vBH approx- in ation.

Fig. 2: Partial density of states (C e 4f-states) obtained by the LSDA-vBH approximation.

Fig. 3: Partial density of states (Fe 3d-states) obtained by the LSDA-vBH approximation.

Fig. 4: Band structure obtained by the LSDA-vBH approximation.

F ig. 5: Total density of states obtained by the LSDA (vBH)+U approximation using the parameter U for cerium and parameters U and J (exchange) for iron.

F ig. 6: Partial density of states (C e 4f-states) obtained by the LSDA (vBH)+U approximation.

F ig. 7: Partial density of states (Fe 3d-states) obtained by the LSDA (vBH)+U approximation.

F ig. 8: B and structure obtained by the LSDA (vBH)+U approximation using the parameter U for cerium and parameters U and J (exchange) for iron.

Table I							
Atoms in the CeFeGe3	C rystallographic P ositions	MT sphere radii (a.u.)	Charge ^a (a.u.)	M agnetic ^a M om ent (_B)	Charge ^b (a.u.)	M agnetic ^b M om ent (_в)	
Ce	(0.0, 0.0, 0.0)	4.1077	-2.4654	-0.00132	-2.3847	-1.1407	
Fe	(1.0,1.0,0.66)	2.4566	-0.3027	0.00033	0.3339	0.6147	
$G e_1$	(0.5,0.0,0.25)	2.5320	1.1212	-0.000005	1.1208	-0.01274	
Ge_2	(1.0,1.0,0.42)	2.6284	1.064	-0.000013	1.0499	-0.02511	
E ₁ *	(0.1224,0.1224,0.5684)	1.1281	-0.1396	-0.000001	-0.1432	-0.00055	
E ₂ *	(0.1224,-0.1224,0.5684)	1.1281	-0.1396	-0.000001	-0.1432	-0.00055	
E 3*	(-0.1224,0.1224,0.5684)	1.1281	-0.1396	-0.000001	-0.1432	-0.00055	
E 4 *	(-0.1224,-0.1224,0.5684)	1.1281	-0.1396	-0.000001	-0.1432	-0.00055	

Positions of the empty spheres that ful llthe ASA condition within the LMTO-ASA approximation.

 $^{\rm a}{\rm A}$ s obtained for the param eters optim ized by m eans of the LSD A –vB H approxim ation.

 $^{\rm b}{\rm A}$ s obtanied via calculations perform ed with the LSDA (vBH)+U aproximation.

Experim ental cell	0 ptim ized cell	% oferror	0 ptim ized cell	% oferror
param eters	param eters	Exp.vsLSDA	param eters	Exp.vsGGS
(A)	(A) LSDA		(A)GGS	
a= b= 4.332	a=b=4.1767	3.71	a=b=4.234	2.314
c= 9.955	c= 9.5981	3.72	c= 9.73	2.312

Table II

This figure "DOS-CEf-CEFEGE3.gif" is available in "gif" format from:

This figure "DOS-Fe.gif" is available in "gif" format from:

This figure "DOSP-CEFEGE3-Cef-U.gif" is available in "gif" format from:

This figure "DOSP-CEFEGE3-Fed-U.gif" is available in "gif" format from:

This figure "DOST-CEFEGE3-U.gif" is available in "gif" format from:

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This figure "EB-CEFEGE3.gif" is available in "gif" format from: